

◆ General Description

GH1200 series unipolar switch Hall position sensor is designed with CMOS technology.

The input control signal is magnetic induction intensity, output is a switch type digital voltage signal, suitable for working with rectangular or cylindrical magnets. When there is no magnetic field control, the output tube of the sensor circuit in this series will be turned off and the output will be at a high level; When the magnetic field strength B is greater than the operating point (BOP), the output switch tube will open and the output will be at a low level; The output state will remain until the magnetic field strength B is lower than the release point (BRP), at which point the output switch will turn off and the output will return to a high level..

◆ Features

- 2.8~ 24V DC Operation Voltage
- CMOS Technology
- Open drain output structure, able to directly interface with logic circuits
- 25mA Output Sink Current
- Operating Temp: -40~ +125°C
- Package: TO-92S/ SOT23-3L/ SOT23
- Lead Free Finish/RoHS Compliant

◆ Applications

- DC brushless motor
- Contactless switch
- Position control
- Isolation testing
- Speed detection

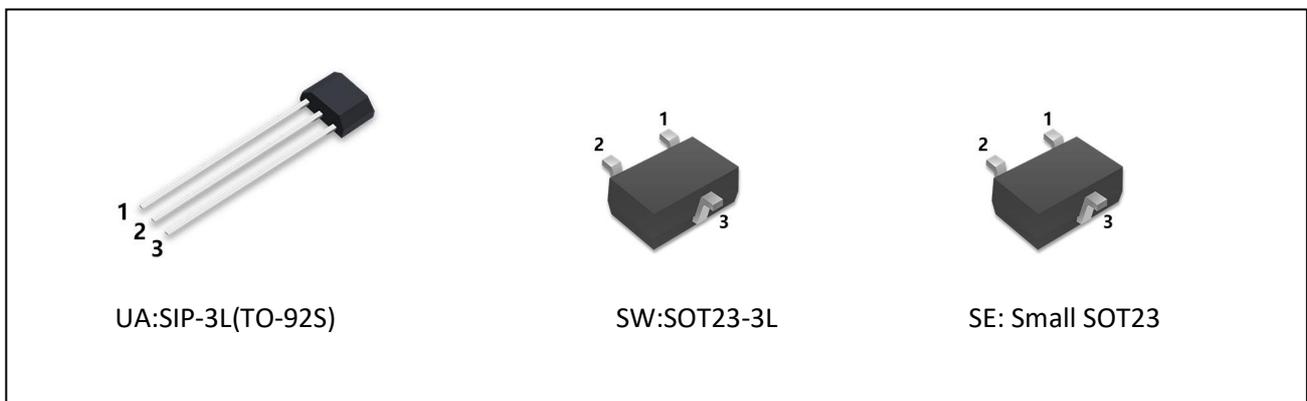


Figure 1. Package Type

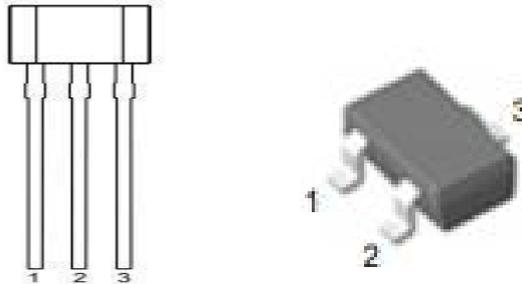
◆ Ordering information

Product	Temp	Package	Magnetic	Packing Type	Quantity
GH1210KUA	K	UA	South pole	Pack	1000pic
GH1210KSW	K	SW	North pole	Tape & Reel	3000pic
GH1220KUA	K	UA	South pole	Pack	1000pic
GH1220KSW	K	SW	North pole	Tape & Reel	3000pic
GH1220KSE	K	SE	South pole	Tape & Reel	3000pic
GH1230KUA	K	UA	South pole	Pack	1000pic
GH1230KSW	K	SW	North pole	Tape & Reel	3000pic

Note

- 1) K stands for temp range -40~125°C
- 2) UA represents the packaging form SIP-3L/TO-92S
- 3) SW represents the packaging form SOT23-3L
- 4) SE represents the packaging form as small SOT23

◆ Pin Configuration



Pin Number		Pin Name	Function
SIP-3L	SOT23-3L/SOT23		
1	1	VCC	Power supply
2	3	GND	Ground
3	2	VOUT	Output

◆ Functional Block Diagram

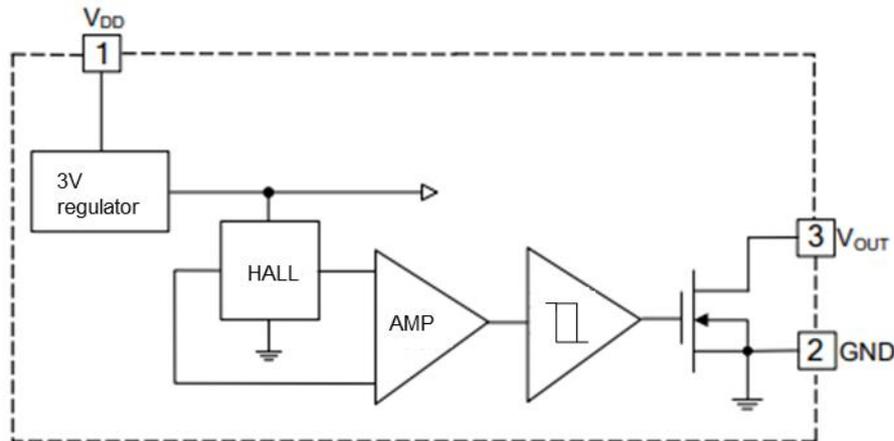


Figure 2. Block Diagram

◆ Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	-0.3~+28	V
Output Off Voltage	V_{OUT}	+32	V
Output Current	I_{OUT}	50	mA
Operation Temperature	T_A	-40~+150	°C
Storage Temperature	T_{ST}	-65~+160	°C
Flux	B	unlimit	Guass

◆ Electrical Characteristics

$V_{DD}=12V$, $T_A=25^{\circ}C$, unless otherwise specified.

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	Operating	2.8	12	24	V
Supply Current	I_{CC}	-	--	2.0	5.0	mA
Output low-level voltage	V_{OUTL}	$I_{OUT}=20mA$, $B > BOP$	--	200	500	mV
Output high-level leakage current	I_{off}	$V_{OUT}=24V$, $B < BRP$	--	<0.1	10	μA
Maximum switching frequency	F_{sw}	$R_L=820\Omega$, $C_L=20pF$	--	10	--	KHz
Output Fall/Up Time	t_f/t_r	$R_L=820\Omega$, $C_L=20pF$	--	0.1	0.5	us

Note:

- 1) If any one of the maximum ratings is exceeded, the device may be damaged.
- 2) The maximum power supply voltage that can work normally must be adjusted according to the constraints of temperature and power consumption.

◆ Magnetic Characteristics

($V_s=12V, T_A=25^{\circ}C$)

GH1210KUA (for South pole)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operate Point	BOP	VCC=12V,TA=25°C	25	45	65	GS
Release Point	BRP	VCC=12V,TA=25°C	10	30	50	GS
Hysteresis	BHYS	VCC=12V,TA=25°C	5	15	25	GS

GH1210KSW (for North pole)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operate Point	BOP	VCC=12V,TA=25°C	-65	-45	-25	GS
Release Point	BRP	VCC=12V,TA=25°C	-50	-30	-10	GS
Hysteresis	BHYS	VCC=12V,TA=25°C	5	15	25	GS

GH1220KUA/GH1220KSE (for South pole)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operate Point	BOP	VCC=12V,TA=25°C	100	120	140	GS
Release Point	BRP	VCC=12V,TA=25°C	70	90	110	GS
Hysteresis	BHYS	VCC=12V,TA=25°C	10	30	50	GS

GH1230KUA (for South pole)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operate Point	BOP	VCC=12V,TA=25°C	15	30	45	GS
Release Point	BRP	VCC=12V,TA=25°C	10	20	30	GS
Hysteresis	BHYS	VCC=12V,TA=25°C	5	10	15	GS

GH1230KSW (for North pole)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operate Point	BOP	VCC=12V,TA=25°C	-45	-35	-15	GS
Release Point	BRP	VCC=12V,TA=25°C	-30	-20	-10	GS
Hysteresis	BHYS	VCC=12V,TA=25°C	5	10	15	GS

Note: 1mT=10Gs

◆ Functional Description

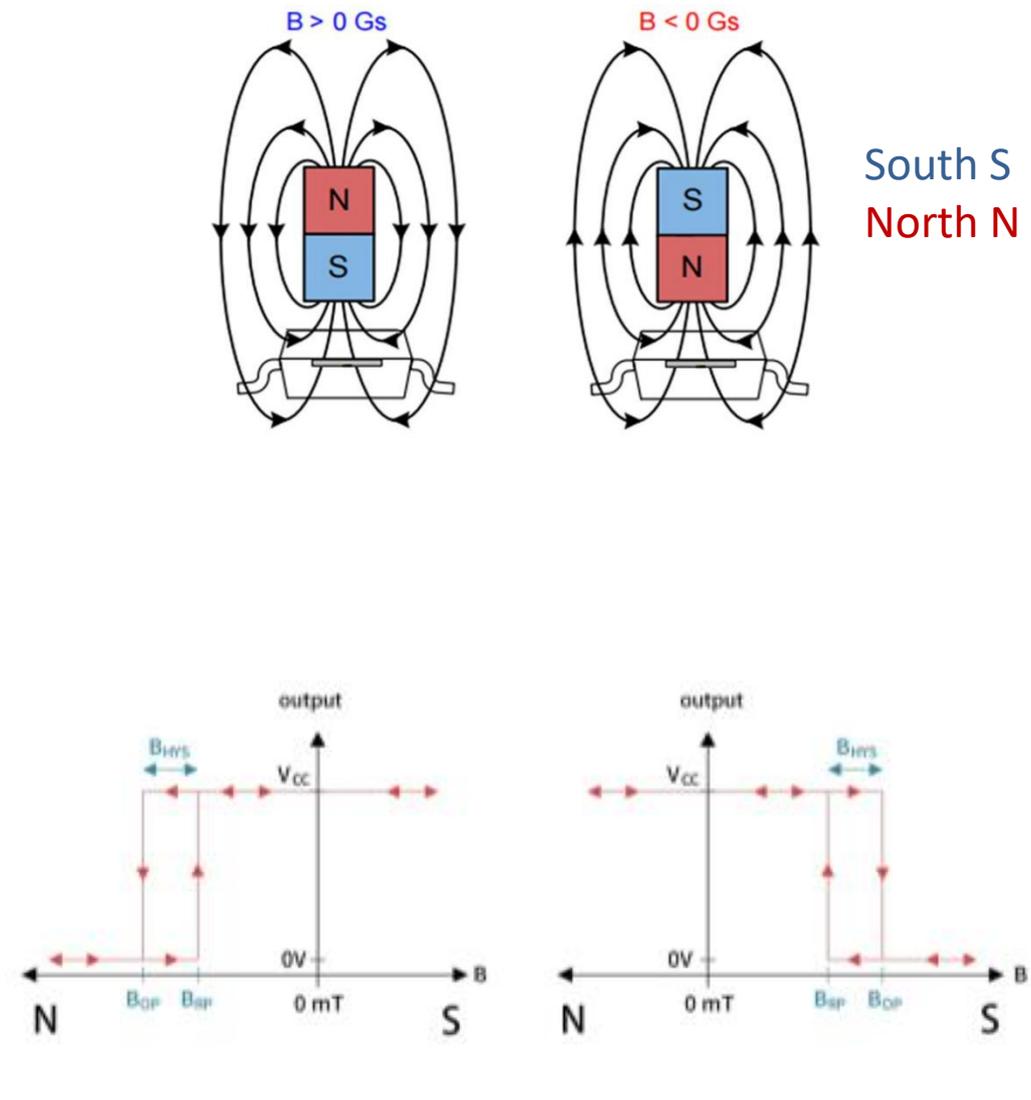


Figure 3. Output characteristics

◆ Typical Application

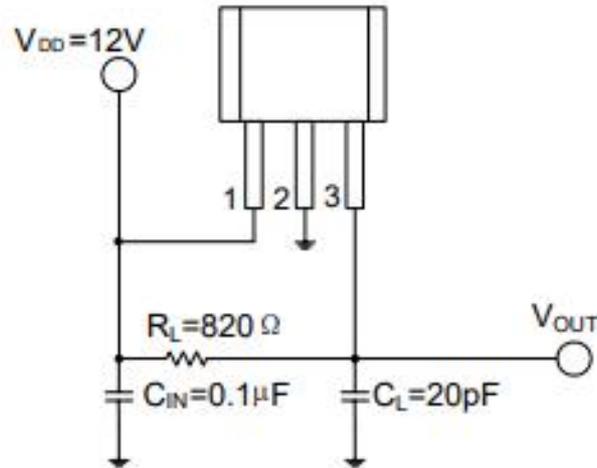


Figure 4. Application

Note:

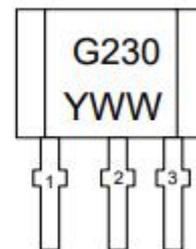
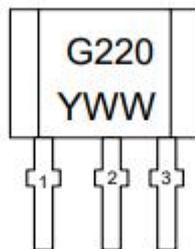
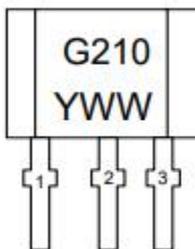
C_{IN} is used to stabilize external power supply;

R_L is the pull-up resistance necessary for open collector output;

C_L is used for filter out the output noise. This capacitor will affect the rise time of the waveform.

◆ Marking Information

1) TO-92S package



G210, G220, G230: for GH1210, GH1220, GH1230

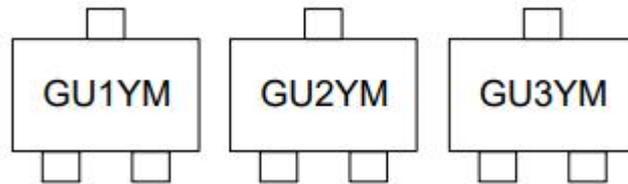
Y: YEAR: "4" = 2024

WW: Nth Week 01~52

GH1210/1220/1230

Unipolar switch Hall position sensor

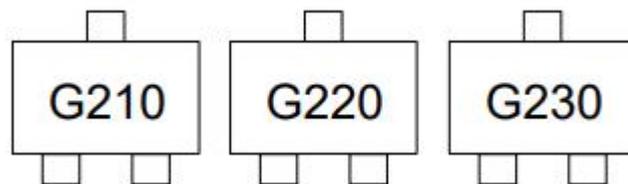
2) SOT23-3L/ SOT23 package



GU1, GU2, GU3: for GH1210, GH1220, GH1230

Y: YEAR: "4" = 2024

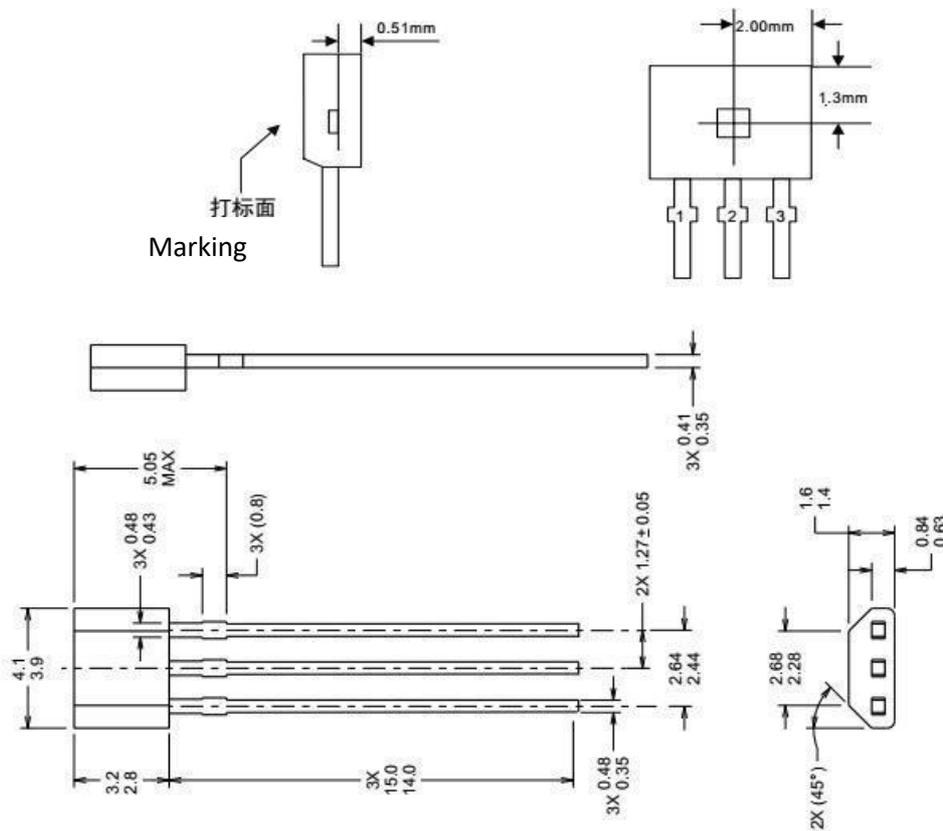
M: Nth Month, A~L



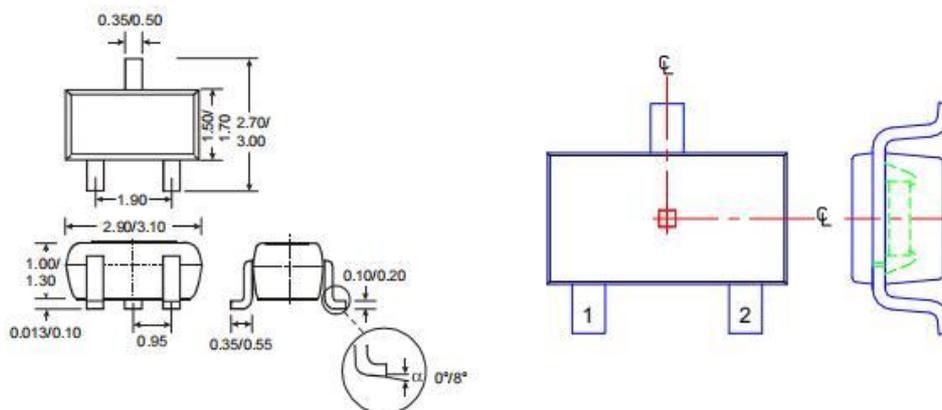
G210, G220, G230: for GH1210, GH1220, GH1230

◆ Package Information

(1) SIP-3L(TO-92S)



(2) SOT23-3L

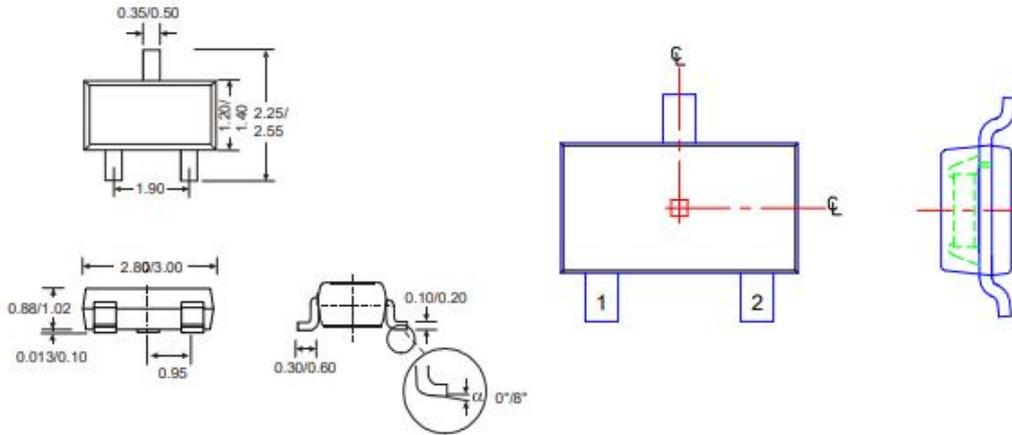


GH1210/1220/1230

Unipolar switch Hall position sensor



(3) SOT23 (Small)



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GoChip Microelectronics is a Chinese high-tech company, dedicating in the R&D, sales, and technical services of sensor chips. It was founded in 2010 and Headquarter in Shanghai, China. Now we have two R&D centers in both Shanghai and Hangzhou city, as well as marketing service networks throughout the country.

Taking the core concept of "Enhance oneself and Surpass expectations", and with more than a decade of persistent technological innovation and high-quality services, GoChip has gradually established a business mode with automotive electronics as the main track and continuously developing in the fields of new energy, industrial automation, consumer electronics. In automotive electronics, we are committed to providing customers with high-performance and reliable sensor chip solutions. Our products are widely used in automotive chassis control systems, engine power systems, and intelligent cabin electric systems. GoChip will continue to increase investment in technological R&D, actively explore the development and promotion of new products, and strive to make greater contributions to China Chip.

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